

## Features

- Industry standard driver replacement
- Improved response times
- Matched rise and fall times
- Reduced clock skew
- Low output impedance
- Low input capacitance
- High noise immunity
- Improved clocking rate
- Low supply current
- Wide operating voltage range

## Applications

- Clock/line drivers
- CCD Drivers
- Ultra-sound transducer drivers
- Power MOSFET drivers
- Switch mode power supplies
- Class D switching amplifiers
- Ultrasonic and RF generators
- Pulsed circuits

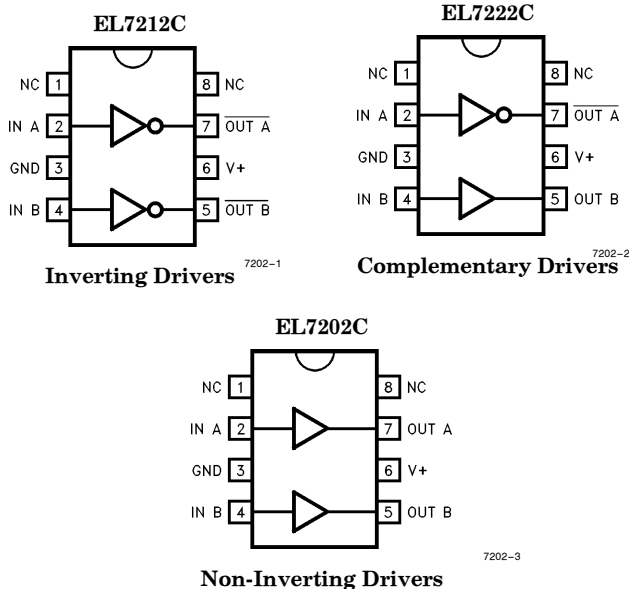
## Ordering Information

Part No.	Temp. Range	Pkg.	Outline #
EL7202CN	-40°C to +85°C	8-Pin P-DIP	MDP0031
EL7202CS	-40°C to +85°C	8-Pin SO	MDP0027
EL7212CN	-40°C to +85°C	8-Pin P-DIP	MDP0031
EL7212CS	-40°C to +85°C	8-Pin SO	MDP0027
EL7222CN	-40°C to +85°C	8-Pin P-DIP	MDP0031
EL7222CS	-40°C to +85°C	8-Pin SO	MDP0027

## General Description

The EL7202C/EL7212C/EL7222C ICs are matched dual-drivers ICs that improve the operation of the industry standard DS0026 clock drivers. The Elantec Versions are very high speed drivers capable of delivering peak currents of 2.0 amps into highly capacitive loads. The high speed performance is achieved by means of a proprietary "Turbo-Driver" circuit that speeds up input stages by tapping the wider voltage swing at the output. Improved speed and drive capability are enhanced by matched rise and fall delay times. These matched delays maintain the integrity of input-to-output pulse-widths to reduce timing errors and clock skew problems. This improved performance is accompanied by a 10 fold reduction in supply currents over bipolar drivers, yet without the delay time problems commonly associated with CMOS devices. Dynamic switching losses are minimized with non-overlapped drive techniques.

## Connection Diagrams



Manufactured under U.S. Patent Nos. 5,334,883, #5,341,047

# EL7202C/EL7212C/EL7222C

## High Speed, Dual Channel Power MOSFET Drivers

### Absolute Maximum Ratings

Supply (V+ to Gnd)	16.5V	Operating Junction Temperature	125°C
Input Pins	−0.3V to +0.3V above V+	Power Dissipation	
Combined Peak Output Current	4A	SOIC	570 mW
Storage Temperature Range	−65°C to +150°C	PDIP	1050 mW
Ambient Operating Temperature	−40°C to +85°C		

#### Important Note:

All parameters having Min/Max specifications are guaranteed. The Test Level column indicates the specific device testing actually performed during production and Quality inspection. Elantec performs most electrical tests using modern high-speed automatic test equipment, specifically the LTX77 Series system. Unless otherwise noted, all tests are pulsed tests, therefore  $T_J = T_C = T_A$ .

Test Level	Test Procedure
I	100% production tested and QA sample tested per QA test plan QCX0002.
II	100% production tested at $T_A = 25^\circ\text{C}$ and QA sample tested at $T_A = 25^\circ\text{C}$ , $T_{MAX}$ and $T_{MIN}$ per QA test plan QCX0002.
III	QA sample tested per QA test plan QCX0002.
IV	Parameter is guaranteed (but not tested) by Design and Characterization Data.
V	Parameter is typical value at $T_A = 25^\circ\text{C}$ for information purposes only.

### DC Electrical Characteristics $T_A = 25^\circ\text{C}$ , $V = 15\text{V}$ unless otherwise specified

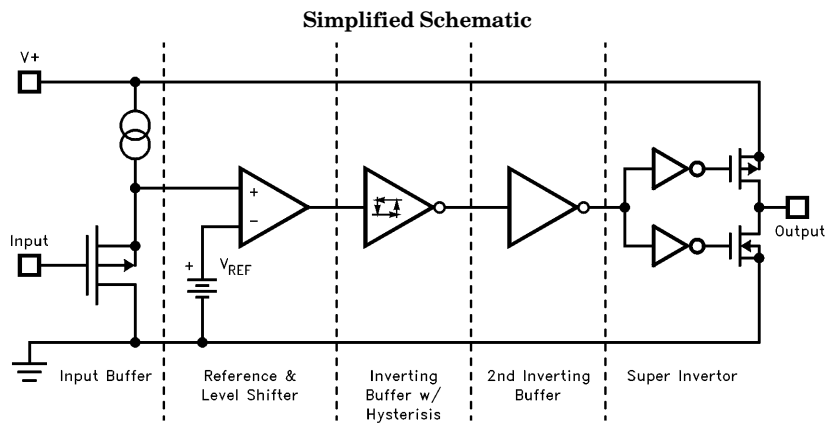
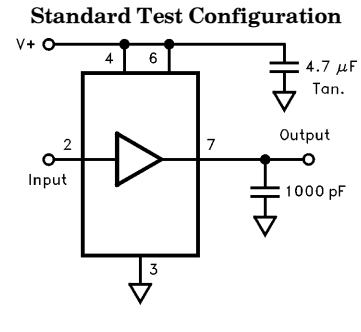
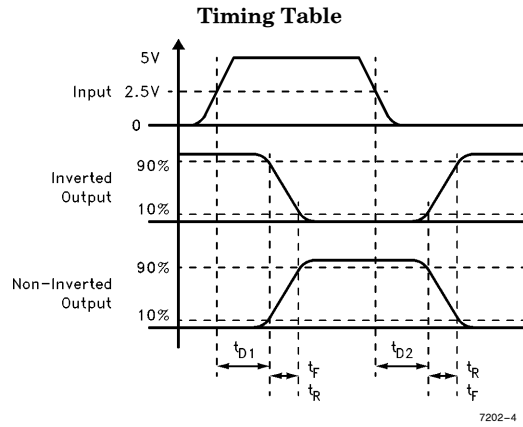
Parameter	Description	Test Conditions	Min	Typ	Max	Test Level	Units
<b>Input</b>							
$V_{IH}$	Logic "1" Input Voltage		2.4			I	V
$I_{IH}$	Logic "1" Input Current	@V+		0.1	10	I	$\mu\text{A}$
$V_{IL}$	Logic "0" Input Voltage				0.8	I	V
$I_{IL}$	Logic "0" Input Current	@0V		0.1	10	I	$\mu\text{A}$
$V_{HVS}$	Input Hysteresis			0.3		V	V
<b>Output</b>							
$R_{OH}$	Pull-Up Resistance	$I_{OUT} = -100\text{ mA}$		3	6	I	$\Omega$
$R_{OL}$	Pull-Down Resistance	$I_{OUT} = +100\text{ mA}$		4	6	I	$\Omega$
$I_{PK}$	Peak Output Current	Source Sink		2 2		IV	A
$I_{DC}$	Continuous Output Current	Source/Sink	100			I	mA
<b>Power Supply</b>							
$I_S$	Power Supply Current	Inputs High/7202 Inputs High/7212 Inputs High/7222		4.5 1 2.5	7.5 2.5 5.0	I I I	mA
$V_S$	Operating Voltage		4.5		15	I	V

# EL7202C/EL7212C/EL7222C

## High Speed, Dual Channel Power MOSFET Drivers

### AC Electrical Characteristics $T_A = 25^\circ\text{C}$ , $V = 15\text{V}$ unless otherwise specified

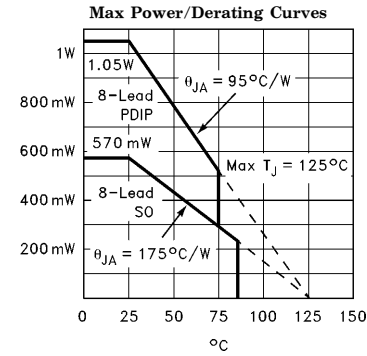
Parameter	Description	Test Conditions	Min	Typ	Max	Test Level	Units
<b>Switching Characteristics</b>							
$t_R$	Rise Time	$C_L = 500\text{ pF}$ $C_L = 1000\text{ pF}$		7.5 10	20	IV	ns
$t_F$	Fall Time	$C_L = 500\text{ pF}$ $C_L = 1000\text{ pF}$		10 13	20	IV	ns
$t_{D1}$	Turn-On Delay Time	See Timing Table		18	25	IV	ns
$t_{D2}$	Turn-Off Delay Time	See Timing Table		20	25	IV	ns



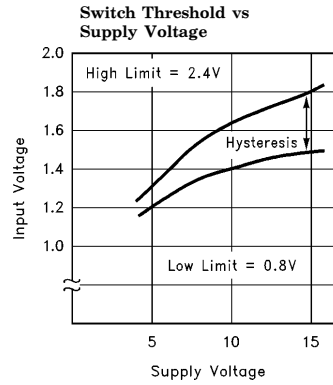
# EL7202C/EL7212C/EL7222C

## High Speed, Dual Channel Power MOSFET Drivers

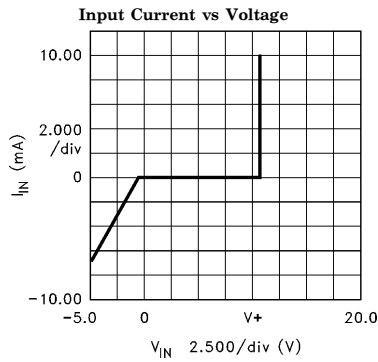
### Typical Performance Curve



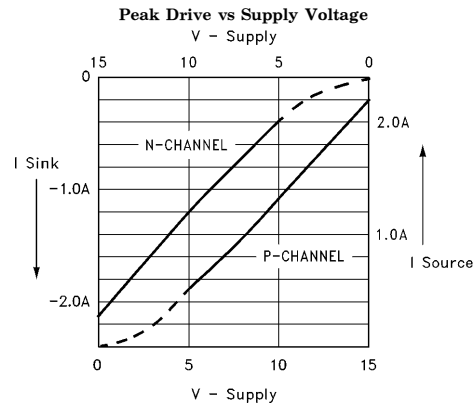
7202-6



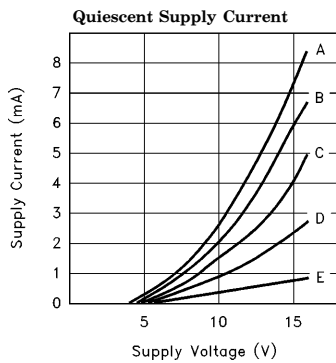
7202-7



7202-8

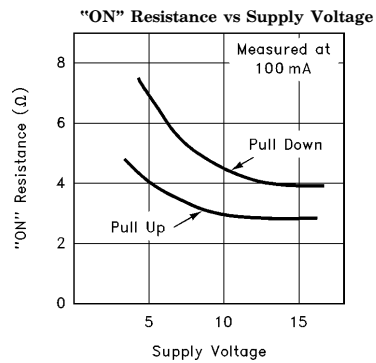


7202-9



CASE:

Device	Input Level	Curve
EL7202	GND	A
EL7202	GND, V+	B
EL7202	V+	C
EL7212	GND	C
EL7212	GND, V+	D
EL7212	V+	E
EL7222	GND	B
EL7222	GND, V+	C
EL7222	V+	D



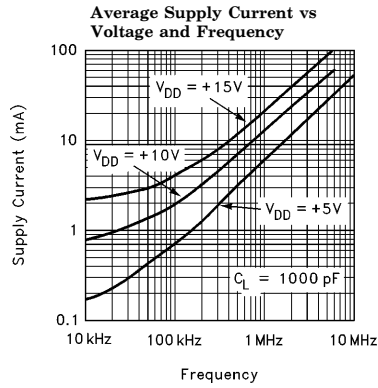
7202-10

7202-11

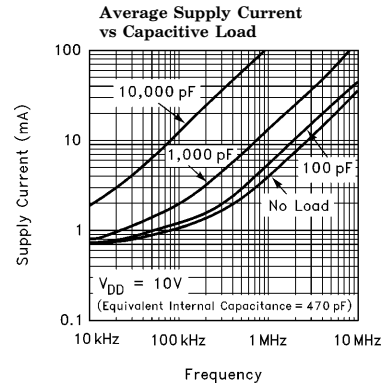
# EL7202C/EL7212C/EL7222C

## High Speed, Dual Channel Power MOSFET Drivers

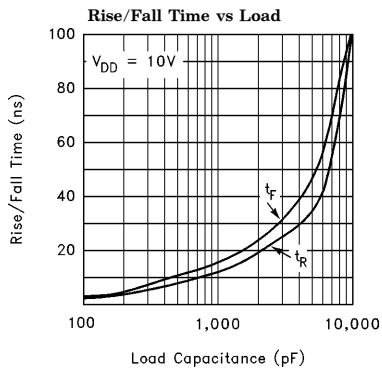
### Typical Performance Curve — Contd.



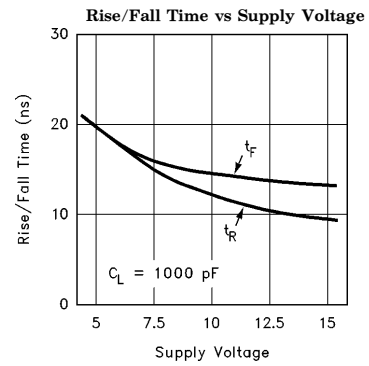
7202-12



7202-13



7202-14

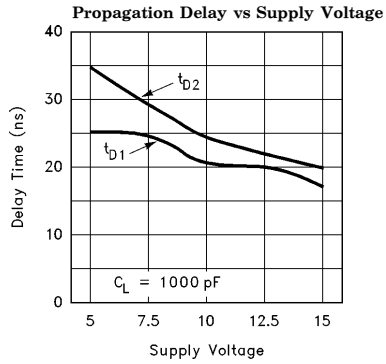


7202-15

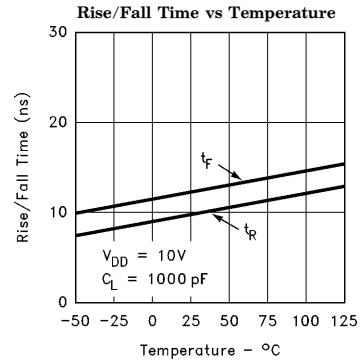
# EL7202C/EL7212C/EL7222C

## High Speed, Dual Channel Power MOSFET Drivers

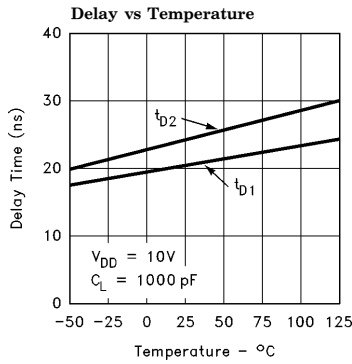
### Typical Performance Curve — Contd.



7202-16



7202-17

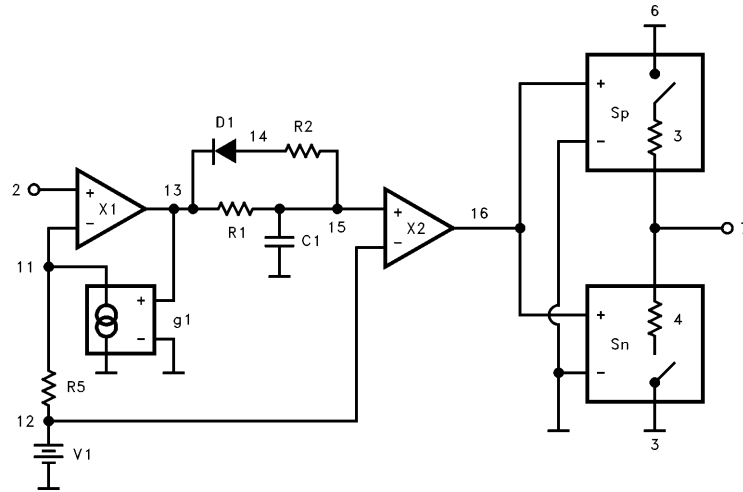


7202-18

# ***EL7202C/EL7212C/EL7222C***

## ***High Speed, Dual Channel Power MOSFET Drivers***

EL7212 Macro Model



7202-20

```

**** EL7212 model ****
*
*      input
*      |
*      |      gnd
*      |      |
*      |      |      Vsupply
*      |      |      |
*      |      |      |      Vout
*      |      |      |      |
.subckt M7212 2      3      6      7
V1 12 3 1.6
R1 13 15 1k
R2 14 15 5k
R5 11 12 100
C1 15 3 43.3 pF
D1 14 13 dmod
X1 13 11 2 3 comp1
X2 16 12 15 3 comp1
sp 6 7 16 3 spmod
sn 7 3 16 3 snmod
g1 11 0 13 0 938μ
.model dmod d
.model spmod vswitch ron=3 roff=2meg von=1 voff=1.5
.model snmod vswitch ron=4 roff=2meg von=3 voff=2
.ends M7212
.subckt comp1 out inp inm vss
e1 out vss table { (v(inp)-v(inm))* 5000 } = (0,0) (3.2,3.2)
Rout out vss 10meg
Rinp inp vss 10meg
Rinm inm vss 10meg
.ends comp1

```

# ***EL7202C/EL7212C/EL7222C***

## ***High Speed, Dual Channel Power MOSFET Drivers***

### **General Disclaimer**

Specifications contained in this data sheet are in effect as of the publication date shown. Elantec, Inc. reserves the right to make changes in the circuitry or specifications contained herein at any time without notice. Elantec, Inc. assumes no responsibility for the use of any circuits described herein and makes no representations that they are free from patent infringement.



### **Elantec, Inc.**

1996 Tarob Court

Milpitas, CA 95035

Telephone: (408) 945-1323

(800) 333-6314

Fax: (408) 945-9305

European Office: 44-71-482-4596

### **WARNING — Life Support Policy**

Elantec, Inc. products are not authorized for and should not be used within Life Support Systems without the specific written consent of Elantec, Inc. Life Support systems are equipment intended to support or sustain life and whose failure to perform when properly used in accordance with instructions provided can be reasonably expected to result in significant personal injury or death. Users contemplating application of Elantec, Inc. products in Life Support Systems are requested to contact Elantec, Inc. factory headquarters to establish suitable terms & conditions for these applications. Elantec, Inc.'s warranty is limited to replacement of defective components and does not cover injury to persons or property or other consequential damages.